

Low drop fixed and adjustable positive voltage regulators

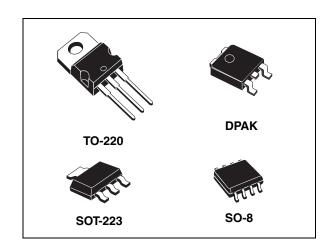
Features

- Low dropout voltage (1 V typ.)
- 2.85 V device performances are suitable for SCSI-2 active termination
- Output current up to 800 mA
- Fixed output voltage of: 1.2 V, 1.8 V, 2.5 V, 2.85 V, 3.0 V, 3.3 V, 5.0 V
- Adjustable version availability (V_{ref} = 1.25 V)
- Internal current and thermal limit
- Available in ± 1% (at 25 °C) and 2% in full temperature range
- Supply voltage rejection: 75 dB (typ.)

Description

The LD1117 is a low drop voltage regulator able to provide up to 800 mA of output current, available even in adjustable version (V_{REF} = 1.25 V). Concerning fixed versions, are offered the following output voltages: 1.2 V, 1.8 V, 2.5 V, 2.85 V, 3.0 V, 3.3 V and 5.0 V. The 2.85 V type is ideal for SCSI-2 lines active termination. The device is supplied in: SOT-223, DPAK, SO-8 and TO-220.

The SOT-223 and DPAK surface mount packages optimize the thermal characteristics even offering a relevant space saving effect.



High efficiency is assured by NPN pass transistor. In fact in this case, unlike than PNP one, the quiescent current flows mostly into the load. Only a very common 10 μ F minimum capacitor is needed for stability. On chip trimming allows the regulator to reach a very tight output voltage tolerance, within \pm 1% at 25°C. The adjustable LD1117 is pin to pin compatible with the other standard. Adjustable voltage regulators maintaining the better performances in terms of drop and tolerance.

Table 1. Device summary

Part numbers						
LD1117XX12	LD1117XX25C	LD1117XX50				
LD1117XX12C	LD1117XX28	LD1117XX50C				
LD1117XX18	LD1117XX30	LD1117XX				
LD1117XX18C	LD1117XX33	LD1117XXC				
LD1117XX25	LD1117XX33C					

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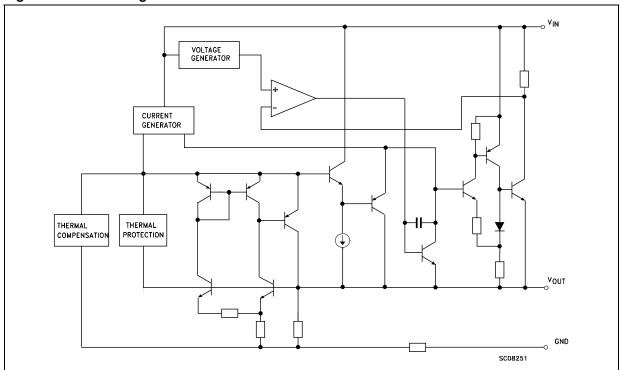
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LD1117xx Diagram

1 Diagram

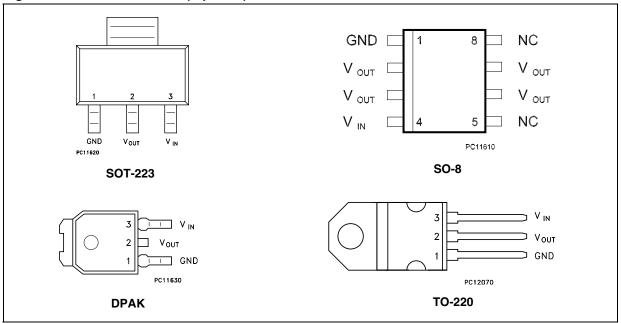
Figure 1. Block diagram



Pin configuration LD1117xx

2 Pin configuration

Figure 2. Pin connections (top view)



Note: The TAB is connected to the V_{OUT} .

LD1117xx Maximum ratings

3 Maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit	
V _{IN} ⁽¹⁾	DC input voltage	15	V	
P _{TOT}	Power dissipation	Power dissipation		
T _{STG}	Storage temperature range	-40 to +150	°C	
т.	Operating junction temperature range	for C Version	-40 to +150	°C
T _{OP}	Operating junction temperature range	for standard Version	0 to +150	°C

^{1.} Absolute maximum rating of V_{IN} = 18 V, when I_{OUT} is lower than 20 mA.

Table 3. Thermal data

Symbol	Parameter	SOT-223	SO-8	DPAK	TO-220	Unit
R _{thJC}	Thermal resistance junction-case	15	20	8	3	°C/W
R _{thJA}	Thermal resistance junction-ambient				50	°C/W

4 Schematic application

Figure 3. Application circuit (for 1.2 V)

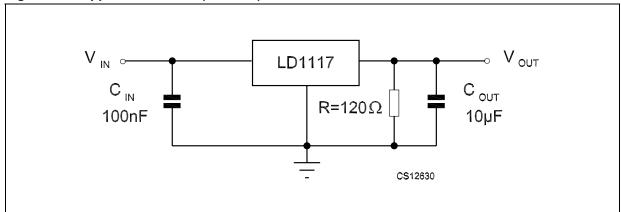
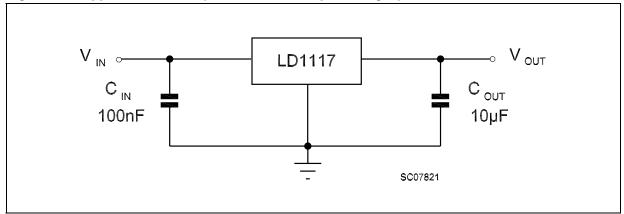


Figure 4. Application circuit (for other fixed output voltages)



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5 Electrical characteristics

Refer to the test circuits, T $_J$ = 0 to 125 °C, C $_O$ = 10 $\mu\text{F},$ R = 120 Ω between GND and OUT pins, unless otherwise specified.

Table 4. Electrical characteristics of LD1117#12

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 3.2 \text{ V}, I_{O} = 10 \text{ mA}, T_{J} = 25^{\circ}\text{C}$	1.188	1.20	1.212	V
V _O	Reference voltage	I _O = 10 to 800 mA V _{in} - V _O = 1.4 to 10 V	1.140	1.20	1.260	V
ΔV _O	Line regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}, I_{O} = 10 \text{ mA}$		0.035	0.2	%
ΔV_{O}	Load regulation	$V_{in} - V_O = 3 \text{ V}, I_O = 10 \text{ to } 800 \text{ mA}$		0.1	0.4	%
ΔV _O	Temperature stability			0.5		%
ΔV_{O}	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage				15	V
I _{adj}	Adjustment pin current	V _{in} ≤ 15 V		60	120	μΑ
Δl_{adj}	Adjustment pin current change	V _{in} - V _O = 1.4 to 10 V I _O = 10 to 800 mA		1	5	μΑ
I _{O(min)}	Minimum load current	V _{in} = 15 V		2	5	mA
Io	Output current	$V_{in} - V_{O} = 5 \text{ V}, T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise (%V _O)	B =10Hz to 10kHz, T _J = 25°C		0.003		%
SVR	Supply voltage rejection	$I_O = 40$ mA, f = 120Hz, $T_J = 25$ °C $V_{in} - V_O = 3$ V, $V_{ripple} = 1$ V _{PP}	60	75		dB
		I _O = 100 mA		1	1.1	
V_d	Dropout voltage	I _O = 500 mA		1.05	1.15	V
		I _O = 800 mA		1.10	1.2	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 5. Electrical characteristics of LD1117#18

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 3.8 \text{ V}, I_{O} = 10 \text{ mA}, T_{J} = 25^{\circ}\text{C}$	1.78	1.8	1.82	V
V _O	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 3.3$ to 8 V	1.76		1.84	V
ΔV_{O}	Line regulation	$V_{in} = 3.3 \text{ to } 8 \text{ V}, I_O = 0 \text{ mA}$		1	6	mV
ΔV _O	Load regulation	$V_{in} = 3.3 \text{ V}, I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV_{O}	Temperature stability			0.5		%
ΔV_{O}	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	$V_{in} \le 8 \text{ V}$		5	10	mA
I _O	Output current	$V_{in} = 6.8 \text{ V}, T_J = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, $T_J = 25^{\circ}C$		100		μV
SVR	Supply voltage rejection	$I_O = 40$ mA, f = 120Hz, $T_J = 25$ °C $V_{in} = 5.5$ V, $V_{ripple} = 1$ V_{PP}	60	75		dB
		I _O = 100 mA		1	1.1	
V_d	Dropout voltage	I _O = 500 mA		1.05	1.15	V
		I _O = 800 mA		1.10	1.2	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 6. Electrical characteristics of LD1117#25

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 4.5 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	2.475	2.5	2.525	V
Vo	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 3.9$ to 10 V	2.45		2.55	V
ΔV_{O}	Line regulation	V_{in} = 3.9 to 10 V, I_O = 0 mA		1	6	mV
ΔV _O	Load regulation	$V_{in} = 3.9 \text{ V}, I_O = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV_{O}	Temperature stability			0.5		%
ΔV_{O}	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	V _{in} ≤ 10 V		5	10	mA
I _O	Output current	V _{in} = 7.5 VT _J = 25°C	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, T _J = 25°C		100		μV
SVR	Supply voltage rejection	$I_O = 40$ mA, f = 120Hz, $T_J = 25$ °C $V_{in} = 5.5$ V, $V_{ripple} = 1$ V_{PP}	60	75		dB
		I _O = 100 mA		1	1.1	
V_d	Dropout voltage	I _O = 500 mA		1.05	1.15	V
		I _O = 800 mA		1.10	1.2	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 7. Electrical characteristics of LD1117#28

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 4.85 \text{ V}, I_{O} = 10 \text{ mA}, T_{J} = 25^{\circ}\text{C}$	2.82	2.85	2.88	V
V _O	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 4.25$ to 10 V	2.79		2.91	V
ΔV _O	Line regulation	$V_{in} = 4.25 \text{ to } 10 \text{ V}, I_{O} = 0 \text{ mA}$		1	6	mV
ΔV _O	Load regulation	$V_{in} = 4.25 \text{ V}, I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV _O	Temperature stability			0.5		%
ΔV _O	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	V _{in} ≤ 10 V		5	10	mA
Io	Output current	V _{in} = 7.85 VT _J = 25°C	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, $T_J = 25^{\circ}C$		100		μV
SVR	Supply voltage rejection	$I_O = 40$ mA, f = 120Hz, $T_J = 25$ °C $V_{in} = 5.85$ V, $V_{ripple} = 1$ V_{PP}	60	75		dB
		I _O = 100 mA		1	1.1	
V_d	Dropout voltage	I _O = 500 mA		1.05	1.15	V
		I _O = 800 mA		1.10	1.2	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 8. Electrical characteristics of LD1117#30

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 5 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	2.97	3	3.03	V
Vo	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 4.5$ to 10 V	2.94		3.06	V
ΔV_{O}	Line regulation	$V_{in} = 4.5 \text{ to } 12 \text{ V}, I_{O} = 0 \text{ mA}$		1	6	mV
ΔV _O	Load regulation	$V_{in} = 4.5 \text{ V}, I_O = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV_{O}	Temperature stability			0.5		%
ΔV_{O}	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	V _{in} ≤ 12 V		5	10	mA
Io	Output current	V _{in} = 8 V, T _J = 25°C	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz,T _J = 25°C		100		μF
SVR	Supply voltage rejection	I_O = 40 mA, f = 120Hz, T_J = 25°C V_{in} = 6 V, V_{ripple} = 1 V_{PP}	60	75		dB
		I _O = 100 mA		1	1.1	
V_d	Dropout voltage	I _O = 500 mA		1.05	1.15	V
		I _O = 800 mA		1.10	1.2	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 9. Electrical characteristics of LD1117#33

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 5.3 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	3.267	3.3	3.333	V
V _O	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 4.75$ to 10 V	3.235		3.365	V
ΔV_{O}	Line regulation	V _{in} = 4.75 to 15 V, I _O = 0 mA		1	6	mV
ΔV _O	Load regulation	$V_{in} = 4.75 \text{ V}, I_{O} = 0 \text{ to } 800 \text{ mA}$		1	10	mV
ΔV_{O}	Temperature stability			0.5		%
ΔV_{O}	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	V _{in} ≤ 15 V		5	10	mA
I _O	Output current	$V_{in} = 8.3 \text{ V}, T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, $T_J = 25^{\circ}C$		100		μV
SVR	Supply voltage rejection	I_O = 40 mA, f = 120Hz, T_J = 25°C V_{in} = 6.3 V, V_{ripple} = 1 V_{PP}	60	75		dB
		I _O = 100 mA		1	1.1	
V_d	Dropout voltage	I _O = 500 mA		1.05	1.15	V
		I _O = 800 mA		1.10	1.2	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 10. Electrical characteristics of LD1117#50

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 7 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	4.95	5	5.05	V
V _O	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 6.5$ to 15 V	4.9		5.1	V
ΔV_{O}	Line regulation	$V_{in} = 6.5 \text{ to } 15 \text{ V}, I_{O} = 0 \text{ mA}$		1	10	mV
ΔV _O	Load regulation	$V_{in} = 6.5 \text{ V}, I_O = 0 \text{ to } 800 \text{ mA}$		1	15	mV
ΔV _O	Temperature stability			0.5		%
ΔV _O	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	V _{in} ≤ 15 V		5	10	mA
I _O	Output current	V _{in} = 10 V, T _J = 25°C	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, T _J = 25°C		100		μV
SVR	Supply voltage rejection	$I_{O} = 40$ mA, f = 120Hz, $T_{J} = 25$ °C $V_{in} = 8$ V, $V_{ripple} = 1$ V _{PP}	60	75		dB
		I _O = 100 mA		1	1.1	
V_d	Dropout voltage	I _O = 500 mA		1.05	1.15	V
		I _O = 800 mA		1.10	1.2	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Refer to the test circuits, T_J = 0 to 125 °C, C_O = 10 $\mu F\!_{,}$ unless otherwise specified.

Table 11. Electrical characteristics of LD1117 (adjustable)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V_{ref}	Reference voltage	V_{in} - V_{O} = 2 V, I_{O} = 10 mA, T_{J} = 25°C	1.238	1.25	1.262	V
V _{ref}	Reference voltage	$I_O = 10 \text{ to } 800 \text{ mA}, V_{in} - V_O = 1.4 \text{ to } 10 \text{ V}$	1.225		1.275	V
ΔV_{O}	Line regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}, I_{O} = 10 \text{ mA}$		0.035	0.2	%
ΔV _O	Load regulation	$V_{in} - V_O = 3 \text{ V}, I_O = 10 \text{ to } 800 \text{ mA}$		0.1	0.4	%
ΔV_{O}	Temperature stability			0.5		%
ΔV _O	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage				15	V
I _{adj}	Adjustment pin current	V _{in} ≤ 15 V		60	120	μΑ
ΔI_{adj}	Adjustment pin current change	$V_{in} - V_{O} = 1.4 \text{ to } 10 \text{ V}, I_{O} = 10 \text{ to } 800 \text{ mA}$		1	5	μΑ
I _{O(min)}	Minimum load current	V _{in} = 15 V		2	5	mA
I _O	Output current	$V_{in} - V_{O} = 5 \text{ V}, T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise (%V _O)	B =10Hz to 10kHz, T _J = 25°C		0.003		%
SVR	Supply voltage rejection	$I_O = 40$ mA, f = 120Hz, $T_J = 25^{\circ}$ C $V_{in} - V_O = 3$ V, $V_{ripple} = 1$ V_{PP}	60	75		dB
		I _O = 100 mA		1	1.1	
V_d	Dropout voltage	I _O = 500 mA		1.05	1.15	V
		I _O = 800 mA		1.10	1.2	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

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Refer to the test circuits, T $_J$ = 0 to 125 °C, C $_O$ = 10 $\mu F,~R$ = 120 Ω between GND and OUT pins, unless otherwise specified.

Table 12. Electrical characteristics of LD1117#12C

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V_{ref}	Reference voltage	V_{in} - V_{O} = 2V, I_{O} = 10 mA, T_{J} = 25°C	1.176	1.20	1.224	V
V _{ref}	Reference voltage	$I_O = 10$ to 800 mA, $V_{in} - V_O = 1.4$ to 10 V	1.120	1.20	1.280	V
ΔV_{O}	Line regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}, I_{O} = 10 \text{ mA}$			1	%
ΔV_{O}	Load regulation	$V_{in} - V_{O} = 3 \text{ V}, I_{O} = 10 \text{ to } 800 \text{ mA}$			1	%
ΔV_{O}	Temperature stability			0.5		%
ΔV_{O}	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage				15	V
I _{adj}	Adjustment pin current	V _{in} ≤ 15 V		60	120	μA
ΔI_{adj}	Adjustment pin current change	V _{in} - V _O = 1.4 to 10 V I _O = 10 to 800 mA		1	5	μΑ
I _{O(min)}	Minimum load current	V _{in} = 15 V		2	5	mA
Io	Output current	V _{in} - V _O = 5 V, T _J = 25°C	800	950	1300	mA
eN	Output noise (%V _O)	B =10Hz to 10kHz, T _J = 25°C		0.003		%
SVR	Supply voltage rejection	$I_O = 40$ mA, f = 120Hz, $T_J = 25$ °C $V_{in} - V_O = 3$ V, $V_{ripple} = 1$ V_{PP}	60	75		dB
		I _O = 100 mA, T _J = 0 to 125°C		1	1.1	
V_d	Dropout voltage	I _O = 500 mA, T _J = 0 to 125°C		1.05	1.2	V
		I _O = 800 mA, T _J = 0 to 125°C		1.10	1.3	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 13. Electrical characteristics of LD1117#18C

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 3.8 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	1.76	1.8	1.84	V
Vo	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 3.9$ to 10 V	1.73		1.87	V
ΔV _O	Line regulation	$V_{in} = 3.3 \text{ to } 8 \text{ V}, I_{O} = 0 \text{ mA}$		1	30	mV
ΔV _O	Load regulation	$V_{in} = 3.3 \text{ V}, I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
ΔV _O	Temperature stability			0.5		%
ΔV _O	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	$V_{in} \le 8 V$		5	10	mA
Io	Output current	V _{in} = 6.8 VT _J = 25°C	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, T _J = 25°C		100		μV
SVR	Supply voltage rejection	$I_O = 40$ mA, f = 120Hz, $T_J = 25$ °C $V_{in} = 5.5$ V, $V_{ripple} = 1$ V_{PP}	60	75		dB
		I _O = 100 mA, T _J = 0 to 125°C		1	1.1	
V_d	Dropout voltage	I _O = 500 mA, T _J = 0 to 125°C		1.05	1.15	V
		I _O = 800 mA, T _J = 0 to 125°C		1.10	1.2	
		I _O = 100 mA			1.1	
V_d	Dropout voltage	I _O = 500 mA			1.2	٧
		I _O = 800 mA			1.3	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 14. Electrical characteristics of LD1117#25C

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V _O	Output voltage	$V_{in} = 4.5 \text{ V}, I_{O} = 10 \text{ mA}, T_{J} = 25^{\circ}\text{C}$	2.45	2.5	2.55	٧
Vo	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 3.9$ to 10 V	2.4		2.6	V
ΔV _O	Line regulation	V_{in} = 3.9 to 10 V, I_O = 0 mA		1	30	mV
ΔV _O	Load regulation	$V_{in} = 3.9 \text{ V}, I_{O} = 0 \text{ to } 800 \text{ mA}$		1	30	mV
ΔV _O	Temperature stability			0.5		%
ΔV _O	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	V _{in} ≤ 10 V		5	10	mA
I _O	Output current	V _{in} = 7.5 VT _J = 25°C	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, T _J = 25°C		100		μV
SVR	Supply voltage rejection	I _O = 40 mA, f = 120Hz, T _J = 25°C V _{in} = 5.5 V, V _{ripple} = 1 V _{PP}	60	75		dB
		I _O = 100 mA, T _J = 0 to 125°C		1	1.1	
V_d	Dropout voltage	$I_{O} = 500 \text{ mA}, T_{J} = 0 \text{ to } 125^{\circ}\text{C}$		1.05	1.15	V
		I _O = 800 mA, T _J = 0 to 125°C		1.10	1.2	
		I _O = 100 mA			1.1	
V_d	Dropout voltage	I _O = 500 mA			1.2	V
		I _O = 800 mA			1.3	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 15. Electrical characteristics of LD1117#33C

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vo	Output voltage	$V_{in} = 5.3 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	3.24	3.3	3.36	V
V _O	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 4.75$ to 10 V	3.16		3.44	V
ΔV_{O}	Line regulation	V _{in} = 4.75 to 15 V, I _O = 0 mA		1	30	mV
ΔV_{O}	Load regulation	$V_{in} = 4.75 \text{ V}, I_O = 0 \text{ to } 800 \text{ mA}$		1	30	mV
ΔV_{O}	Temperature stability			0.5		%
ΔV_{O}	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	V
I _d	Quiescent current	V _{in} ≤ 15 V		5	10	mA
Io	Output current	$V_{in} = 8.3 \text{ V}, T_J = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, $T_J = 25^{\circ}C$		100		μV
SVR	Supply voltage rejection	$I_O = 40$ mA, f = 120Hz, $T_J = 25$ °C $V_{in} = 6.3$ V, $V_{ripple} = 1$ V_{PP}	60	75		dB
		I _O = 100 mA, T _J = 0 to 125°C		1	1.1	
V_{d}	Dropout voltage	I _O = 500 mA, T _J = 0 to 125°C		1.05	1.15	V
		I _O = 800 mA, T _J = 0 to 125°C		1.10	1.2	
		I _O = 100 mA			1.1	
V_{d}	Dropout voltage	I _O = 500 mA			1.2	V
		I _O = 800 mA			1.3	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 16. Electrical characteristics of LD1117#50C

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V _O	Output voltage	$V_{in} = 7 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	4.9	5	5.1	٧
Vo	Output voltage	$I_{O} = 0$ to 800 mA, $V_{in} = 6.5$ to 15 V	4.8		5.2	V
ΔV _O	Line regulation	V _{in} = 6.5 to 15 V, I _O = 0 mA		1	50	mV
ΔV _O	Load regulation	V _{in} = 6.5 V, I _O = 0 to 800 mA		1	50	mV
ΔV _O	Temperature stability			0.5		%
ΔV _O	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage	I _O = 100 mA			15	٧
I _d	Quiescent current	V _{in} ≤ 15 V		5	10	mA
I _O	Output current	V _{in} = 10 V, T _J = 25°C	800	950	1300	mA
eN	Output noise voltage	B =10Hz to 10kHz, T _J = 25°C		100		μV
SVR	Supply voltage rejection	I _O = 40 mA, f = 120Hz, T _J = 25°C V _{in} = 8 V, V _{ripple} = 1 V _{PP}	60	75		dB
		I _O = 100 mA, T _J = 0 to 125°C		1	1.1	
V_d	Dropout voltage	I _O = 500 mA, T _J = 0 to 125°C		1.05	1.15	V
		I _O = 800 mA, T _J = 0 to 125°C		1.10	1.2	
		I _O = 100 mA			1.1	
V_d	Dropout voltage	I _O = 500 mA			1.2	V
		I _O = 800 mA			1.3	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

Table 17. Electrical characteristics of LD1117C (adjustable)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
V_{ref}	Reference voltage	V_{in} - V_O = 2 V, I_O = 10 mA, T_J = 25°C	1.225	1.25	1.275	V
V _{ref}	Reference voltage	$I_O = 10 \text{ to } 800 \text{ mA}, V_{in} - V_O = 1.4 \text{ to } 10 \text{ V}$	1.2		1.3	V
ΔV _O	Line regulation	$V_{in} - V_{O} = 1.5 \text{ to } 13.75 \text{ V}, I_{O} = 10 \text{ mA}$			1	%
ΔV _O	Load regulation	$V_{in} - V_O = 3 \text{ V}, I_O = 10 \text{ to } 800 \text{ mA}$			1	%
ΔV _O	Temperature stability			0.5		%
ΔV _O	Long term stability	1000 hrs, T _J = 125°C		0.3		%
V _{in}	Operating input voltage				15	V
I _{adj}	Adjustment pin current	V _{in} ≤ 15 V		60	120	μΑ
ΔI_{adj}	Adjustment pin current change	V_{in} - V_{O} = 1.4 to 10 V, I_{O} = 10 to 800 mA		1	10	μΑ
I _{O(min)}	Minimum load current	V _{in} = 15 V		2	5	mA
Io	Output current	$V_{in} - V_{O} = 5 \text{ V}, T_{J} = 25^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise (%V _O)	B =10Hz to 10kHz, T _J = 25°C		0.003		%
SVR	Supply voltage rejection	$I_{O} = 40$ mA, f = 120Hz, $T_{J} = 25^{\circ}$ C $V_{in} - V_{O} = 3$ V, $V_{ripple} = 1$ V_{PP}	60	75		dB
		I _O = 100 mA, T _J = 0 to 125°C		1	1.1	
V_d	Dropout voltage	I _O = 500 mA, T _J = 0 to 125°C		1.05	1.15	V
		I _O = 800 mA, T _J = 0 to 125°C		1.10	1.2	
		I _O = 100 mA			1.1	
V_d	Dropout voltage	I _O = 500 mA			1.2	V
		I _O = 800 mA			1.3	
	Thermal regulation	T _a = 25°C, 30ms Pulse		0.01	0.1	%/W

LD1117xx Typical application

6 Typical application

Figure 5. Negative supply

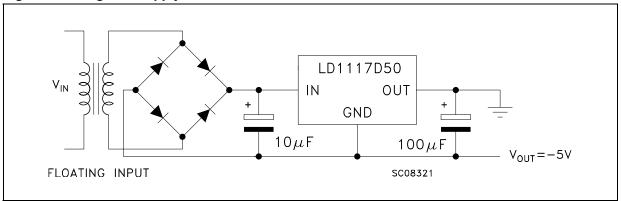


Figure 6. Active terminator for SCSI-2 bus

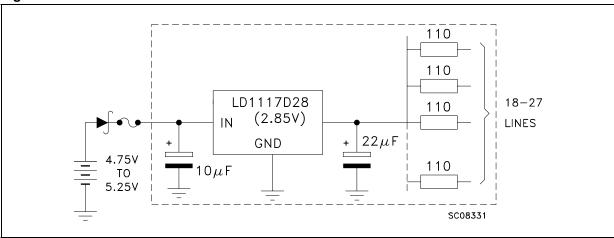
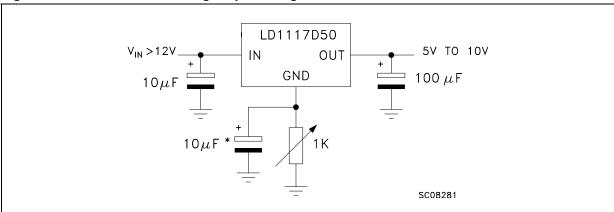


Figure 7. Circuit for increasing output voltage



Typical application LD1117xx

Figure 8. Voltage regulator with reference

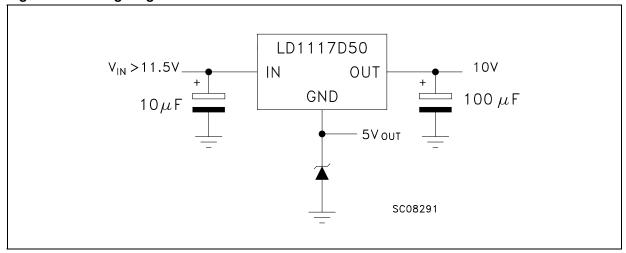
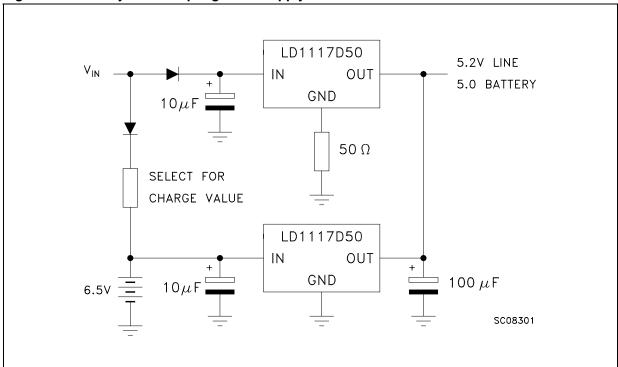


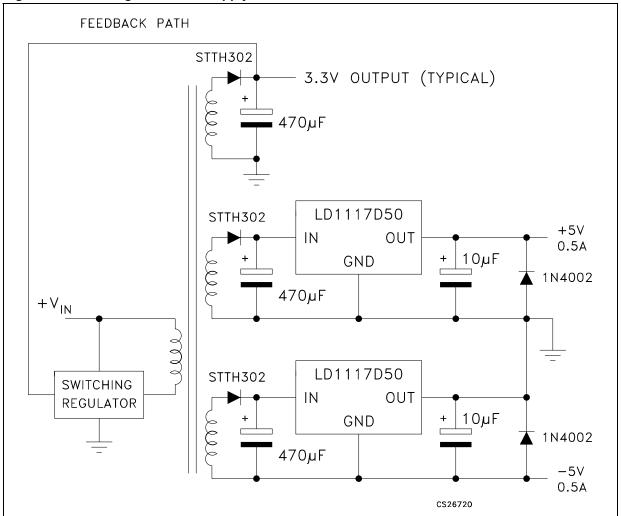
Figure 9. Battery backed-up regulated supply



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LD1117xx Typical application

Figure 10. Post-regulated dual supply



7 LD1117 adjustable: application note

The LD1117 Adjustable has a thermal stabilized 1.25 \pm 0.012 V reference voltage between the OUT and ADJ pins. $I_{AD,I}$ is 60 μ A typ. (120 μ A max.) and $\Delta I_{AD,I}$ is 1 μ A typ. (5 μ A max.).

R1 is normally fixed to 120 Ω . From *Figure 10* we obtain:

$$V_{OUT} = V_{REF} + R2 (I_{ADJ} + I_{R1}) = V_{REF} + R2 (I_{ADJ} + V_{REF} / R_1) = V_{REF} (1 + R2 / R_1) + R2 x I_{ADJ}$$

In normal application R2 value is in the range of few $k\Omega$, so the R2 x I_{ADJ} product could not be considered in the V_{OUT} calculation; then the above expression becomes:

$$V_{OUT} = V_{REF} (1 + R2 / R1).$$

In order to have the better load regulation it is important to realize a good Kelvin connection of R1 and R2 resistors. In particular R1 connection must be realized very close to OUT and ADJ pin, while R2 ground connection must be placed as near as possible to the negative Load pin. Ripple rejection can be improved by introducing a 10 μ F electrolytic capacitor placed in parallel to the R2 resistor (see *Figure 11*).

Figure 11. Adjustable output voltage application

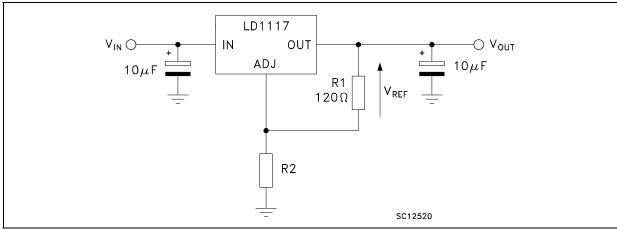
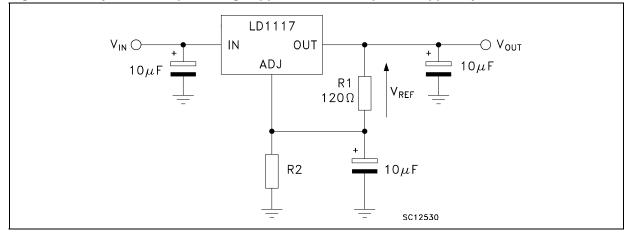


Figure 12. Adjustable output voltage application with improved ripple rejection



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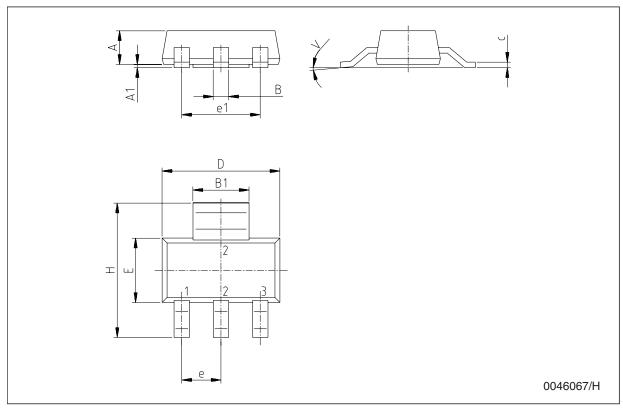
8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.



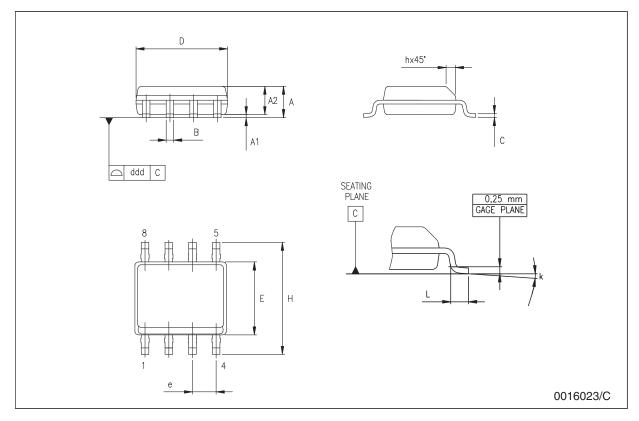
SOT-223 mechanical data

Dim.		mm.		mils.			
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.8			70.9	
A1	0.02		0.1	0.8		3.9	
В	0.6	0.7	0.85	23.6	27.6	33.5	
B1	2.9	3	3.15	114.2	118.1	124.0	
С	0.24	0.26	0.35	9.4	10.2	13.8	
D	6.3	6.5	6.7	248.0	255.9	263.8	
е		2.3			90.6		
e1		4.6			181.1		
E	3.3	3.5	3.7	129.9	137.8	145.7	
Н	6.7	7	7.3	263.8	275.7	287.5	
V			10°			10°	



SO-8 mechanical data

Dim.		mm.		inch.		
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
е		1.27			0.050	
Н	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	8° (max.)					
ddd			0.1			0.04



"GATE" Note 6 THERMAL PAD c2 - E1 L2 D1 Н L4 A 1 Note 7 b(2x)R – e 1-С SEATING PLANE A2 (L1) *V2* GAUGE PLANE 0,25 0068772/G

Figure 13. Drawing dimension DPAK (type STD-ST)

THERMAL PAD c2 E1 -L2 D1 D Н A 1 <u>b</u> (2x) R - e - (2x)С SEATING PLANE A2 V2 GAUGE PLANE 0,51 0068772/G

Figure 14. Drawing dimension DPAK (type Fujitsu-subcon.)

Ε THERMAL PAD c2 - E1 L2 D1 D L4 A 1 **b**(2x) — е 1— С SEATING PLANE L1 GAUGE PLANE 0,25 0068772/G

Figure 15. Drawing dimension DPAK (type IDS-subcon.)

Table 18. DPAK mechanical data

	Type STD-ST			Type Fujitsu-subcon.			Тур	oe IDS-sub	con
Dim.		mm.		mm.		mm.			
	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.20		2.40	2.25	2.30	2.35	2.19		2.38
A1	0.90		1.10	0.96		1.06	0.89		1.14
A2	0.03		0.23	0		0.10	0.03		0.23
b	0.64		0.90	0.76		0.86	0.64		0.88
b4	5.20		5.40	5.28		5.38	5.21		5.46
С	0.45		0.60	0.46		0.56	0.46		0.58
c2	0.48		0.60	0.46		0.56	0.46		0.58
D	6.00		6.20	6.05		6.15	5.97		6.22
D1		5.10		5.27		5.47		5.20	
E	6.40		6.60	6.55	6.60	6.65	6.35		6.73
E1		4.70			4.77			4.70	
е		2.28		2.23	2.28	2.33		2.28	
e1	4.40		4.60				4.51		4.61
Н	9.35		10.10	9.90		10.30	9.40		10.42
L	1.00			1.40		1.60	0.90		
L1		2.80					2.50		2.65
L2		0.80		1.03		1.13	0.89		1.27
L4	0.60		1.00	0.70		0.90	0.64		1.02
R		0.20			0.40			0.20	
V2	0°		8°	0°		8°	0°		8°

Note: The DPAK package coming from the two subcontractors (Fujitsu and IDS) are fully compatible with the ST's package suggested footprint.

Figure 16. DPAK footprint recommended data

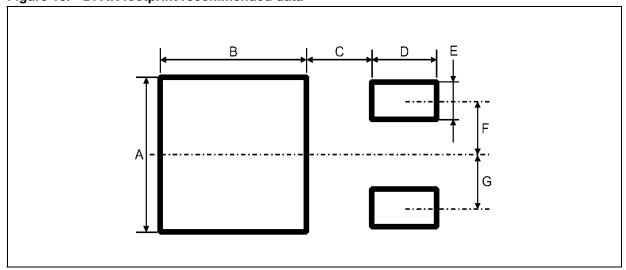


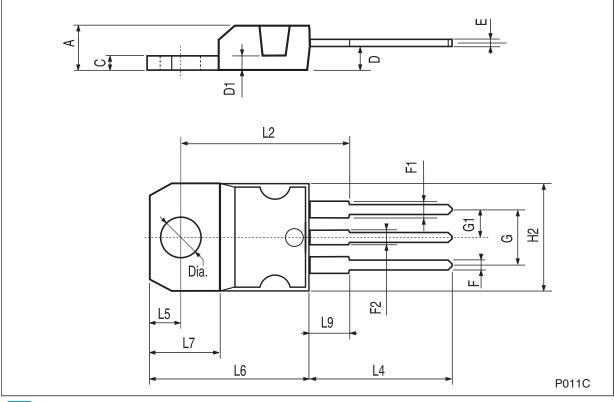
Table 19. Footprint data

Values							
	mm.	inch.					
A	6.70	0.264					
В	6.70	0.64					
С	1.8	0.070					
D	3.0	0.118					
E	1.60	0.063					
F	2.30	0.091					
G	2.30	0.091					

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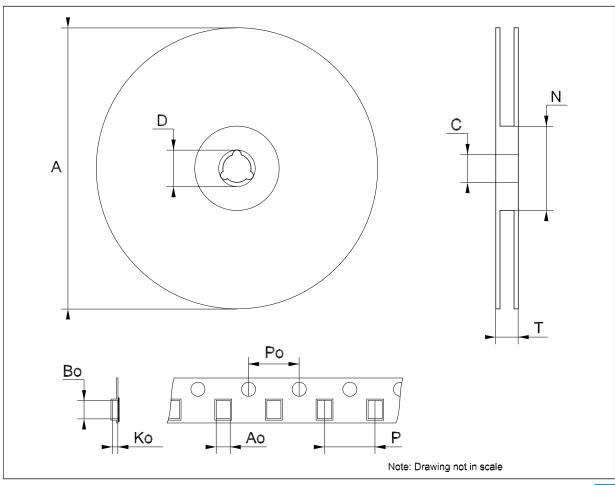
TO.	.220	mac	hanic	al data
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Dim.		mm.			inch.			
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	4.40		4.60	0.173		0.181		
С	1.23		1.32	0.048		0.051		
D	2.40		2.72	0.094		0.107		
D1		1.27			0.050			
E	0.49		0.70	0.019		0.027		
F	0.61		0.88	0.024		0.034		
F1	1.14		1.70	0.044		0.067		
F2	1.14		1.70	0.044		0.067		
G	4.95		5.15	0.194		0.203		
G1	2.4		2.7	0.094		0.106		
H2	10.0		10.40	0.393		0.409		
L2		16.4			0.645			
L4	13.0		14.0	0.511		0.551		
L5	2.65		2.95	0.104		0.116		
L6	15.25		15.75	0.600		0.620		
L7	6.2		6.6	0.244		0.260		
L9	3.5		3.93	0.137		0.154		
DIA.	3.75		3.85	0.147		0.151		



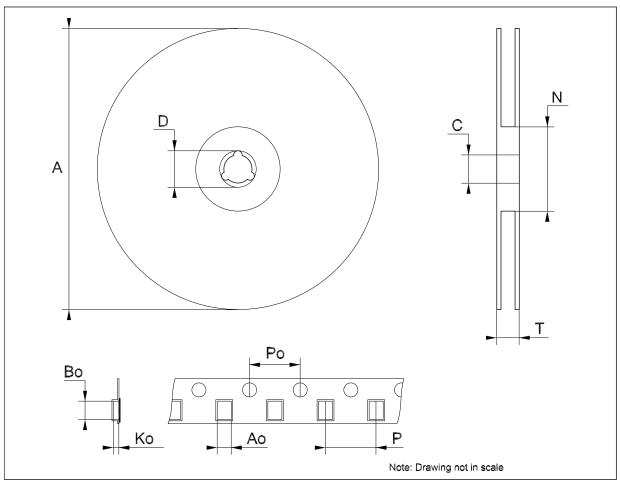
Tane	ጼ	reel	SOT223	mechanical	data
Iape	α	ICCI	301223	IIICUIIaiiiCai	uata

Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
Т			14.4			0.567
Ao	6.73	6.83	6.93	0.265	0.269	0.273
Во	7.32	7.42	7.52	0.288	0.292	0.296
Ko	1.78		2	0.070		0.078
Po	3.9	4.0	4.1	0.153	0.157	0.161
Р	7.9	8.0	8.1	0.311	0.315	0.319

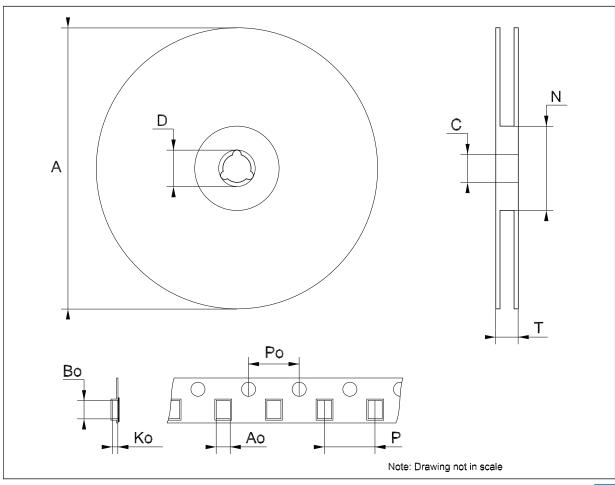


Tape & reel SO-8 mechanical data

Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	8.1		8.5	0.319		0.335
Во	5.5		5.9	0.216		0.232
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8	13.0	13.2	0.504	0.512	0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.80	6.90	7.00	0.268	0.272	0.2.76
Во	10.40	10.50	10.60	0.409	0.413	0.417
Ko	2.55	2.65	2.75	0.100	0.104	0.105
Po	3.9	4.0	4.1	0.153	0.157	0.161
Р	7.9	8.0	8.1	0.311	0.315	0.319



LD1117xx Order codes

9 Order codes

Table 20. Order codes

Packages						
SOT-223	SO-8	DPAK	DPAK (T & R)	TO-220	Output voltages	
LD1117S12TR	LD1117D12TR ⁽¹⁾	LD1117DT12 ⁽¹⁾	LD1117DT12TR		1.2 V	
LD1117S12CTR	LD1117D12CTR ⁽¹⁾	LD1117DT12C (1)		LD1117V12C ⁽¹⁾	1.2 V	
LD1117S18TR	LD1117D18TR ⁽¹⁾		LD1117DT18TR	LD1117V18	1.8 V	
LD1117S18CTR	LD1117D18CTR ⁽¹⁾		LD1117DT18CTR	LD1117V18C ⁽¹⁾	1.8 V	
LD1117S25TR	LD1117D25TR ⁽¹⁾		LD1117DT25TR		2.5 V	
LD1117S25CTR	LD1117D25CTR (1)		LD1117DT25CTR		2.5 V	
			LD1117DT28TR		2.85 V	
LD1117S30TR					3 V	
LD1117S33TR	LD1117D33TR		LD1117DT33TR	LD1117V33	3.3 V	
LD1117S33CTR	LD1117D33CTR		LD1117DT33CTR	LD1117V33C	3.3 V	
LD1117S50TR			LD1117DT50TR	LD1117V50	5 V	
LD1117S50CTR			LD1117DT50CTR		5 V	
LD1117STR	LD1117DTR ⁽¹⁾		LD1117DTTR	LD1117V	ADJ from 1.25 to 15V	
LD1117SC-R	LD1117DC-R (1)	LD1117DTC ⁽¹⁾	LD1117DTC-R	LD1117VC ⁽¹⁾	ADJ from 1.25 to 15V	

^{1.} Available on request.

Revision history LD1117xx

10 Revision history

Table 21. Document revision history

Date	Revision	Changes
22-Sep-2004	15	Add new part number #12C; typing error: note on table 2.
25-Oct-2004	16	Add V _{ref} reference voltage on table 12.
18-Jul-2005	17	The DPAK mechanical data updated.
25-Nov-2005	18	The TO220FM package removed.
14-Dec-2005	19	The T _{op} on table 2 updated.
06-Dec-2006	20	DPAK mechanical data updated and added footprint data.
05-Apr-2007	21	Order codes updated.
30-Nov-2007	22	Added Table 1.
16-Apr-2008	23	Modified: Table 20 on page 39.
08-Jul-2008	24	Added note 1. on page 7.
30-Mar-2009	25	Modified: V _{IN} max value <i>Table 5 on page 10</i> and <i>Figure 10 on page 25</i> .
29-Jul-2009	26	Modified: Table 20 on page 39.

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